NSN 5961-01-129-4602

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-129-4602 **Inclosure Material:** Ceramic **Overall Length:** 3.250 inches **Overall Diameter:** 1.231 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Thread Size:** 0.750 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1100.0 nonrepetitive peak reverse voltage **Current Rating Per Characteristic:** 4500.00 amperes forward current, total rms watts **Power Rating Per Characteristic:** 16.0 watts small-signal input power, common-collector blank **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0